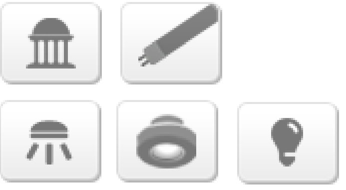
Mid-Power LED - 3030E Series

STW8C12E-E0

S1W0-3030xx8003-00000000-00011



Product Brief

Description

- This White Colored surface-mount LED comes in standard package dimension. Package Size : 3.3x3.0x0.75mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

Features and Benefits

- Thermally Enhanced Package Design
- Mid Power to High Power up to 0.6W
- Max. Driving Current 200mA
- Compact Package Size
- High Color Quality with CRI Min.80, R9>0
- Pb-free Reflow Soldering Application

Key Applications

- Replacement lamps – Bulb, Tube
- Commercial
- Industrial
- Residential

Table 1. Product Selection Table

Part Number	Color	Nominal CCT	Order Code	CRI Min
STW8C12E-E00000IZ	Cool White	6500K	S1W0-3030658003-00000000-00011	80
		5700K	S1W0-3030578003-00000000-00011	
		5000K	S1W0-3030508003-00000000-00011	
	Neutral White	4000K	S1W0-3030408003-00000000-00011	
	Warm White	3500K	S1W0-3030358003-00000000-00011	
		3000K	S1W0-3030308003-00000000-00011	
		2700K	S1W0-3030278003-00000000-00011	

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Performance Characteristics

Table 2. Product Selection Guide, I_F = 65mA , T_j = 25ºC, RH30%

Typ. CRI, Ra	Nominal CCT [K] [1]	Min. Flux [lm]	Typ. Luminous Flux ΦV [2] [lm] @65mA	Typ. Luminous Efficacy [lm/W] @65mA	PPF [μmol/s] @65mA	PPE [μmol/J] @65mA
80	6500	37.5	39.5	226.6	0.559	3.21
	5700	37.5	39.9	228.9	0.555	3.19
	5000	39.0	40.7	233.6	0.550	3.16
	4000	39.0	40.5	232.5	0.547	3.14
	3500	37.5	39.8	228.4	0.540	3.11
	3000	37.5	39.4	226.0	0.532	3.06
	2700	37.5	38.7	221.9	0.526	3.03

Notes :

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

(2) Seoul Semiconductor maintains a tolerance of ±5% on flux and power measurements.

Performance Characteristics

Table 3. Characteristics, I_F=65mA, T_j= 25ºC, RH30%

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Forward Current	I_F	5	65	-	mA
Forward Voltage[1]	V_F	2.60	2.68	2.80	V
CRI[1]	R_a	80		90	
R9	R_9	0			
Viewing Angle [2]	$2\Theta_{1/2}$	-	120	-	Deg.
Thermal resistance (J to S) [3]	$R\theta_{J\text{-}S}$	-	7.5		℃/W
Turn-on voltage	V_F (1uA)	1.9	-	2.7	V
ESD Sensitivity(HBM) [4]	-	Class 3A JEDEC JS-001-2017			

Table 4. Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	I_F	200	mA
Power Dissipation	P_D	0.6	W
Junction Temperature[5]	T_j	125	ºC
Operating Temperature	T_{opr}	-40 ~ + 85	ºC
Storage Temperature	T_{stg}	-40 ~ + 100	ºC

Notes :

(1) Tolerance : VF :±0.1V, Flux :±5%, Ra :±2, x,y :±0.005

(2) $2\Theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 of the peak intensity.

(3) Thermal resistance : Rth_{JS} (Junction / solder)

(4) A zener diode is included for ESD Protection.

(5) $T_J = T_S + R\theta_{J\text{-}S} * P$

T_J [℃] = LED Junction Temperature
T_S [℃] = LED Solder Temperature
P [W] = $I_F * V_F$

• LED's properties might be different from suggested values like above and below tables if operation condition will be exceeded our parameter range. Care is to be taken that power *dissipation does not* exceed the absolute maximum rating of the product.

• Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.

• All measurements were made under the standardized environment of Seoul Semiconductor.

Characteristics Graph

Fig 1. Color Spectrum, T_j = 25ºC

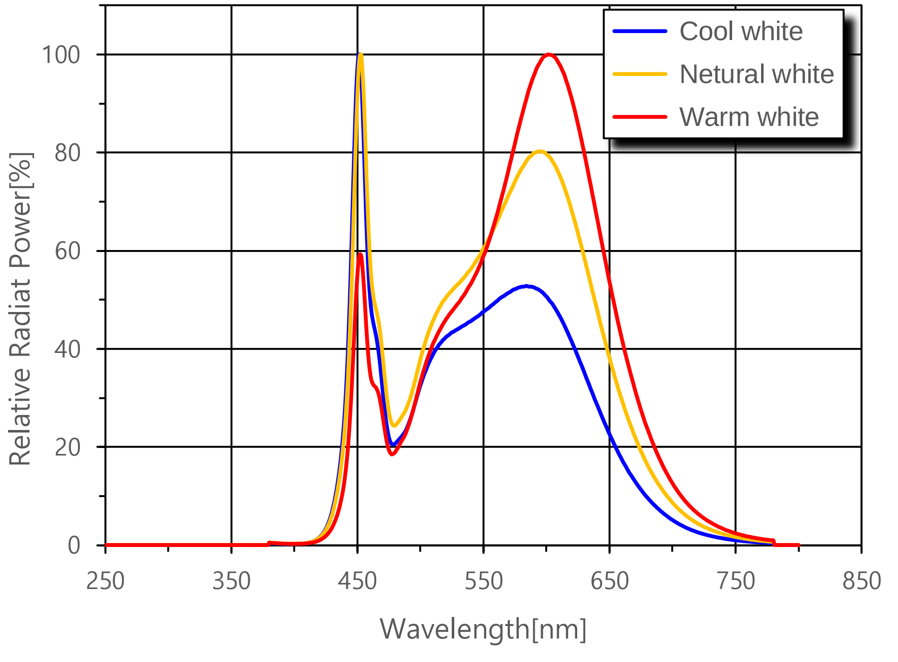
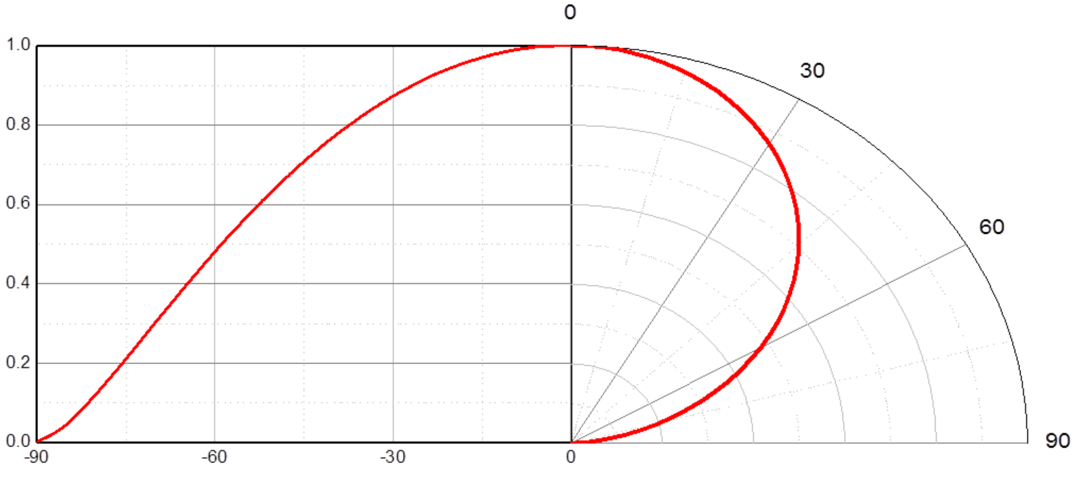


Fig 2. Radiant Pattern, T_j = 25ºC



Characteristics Graph

Fig 3. Forward Voltage vs. Forward Current, T_j = 25ºC

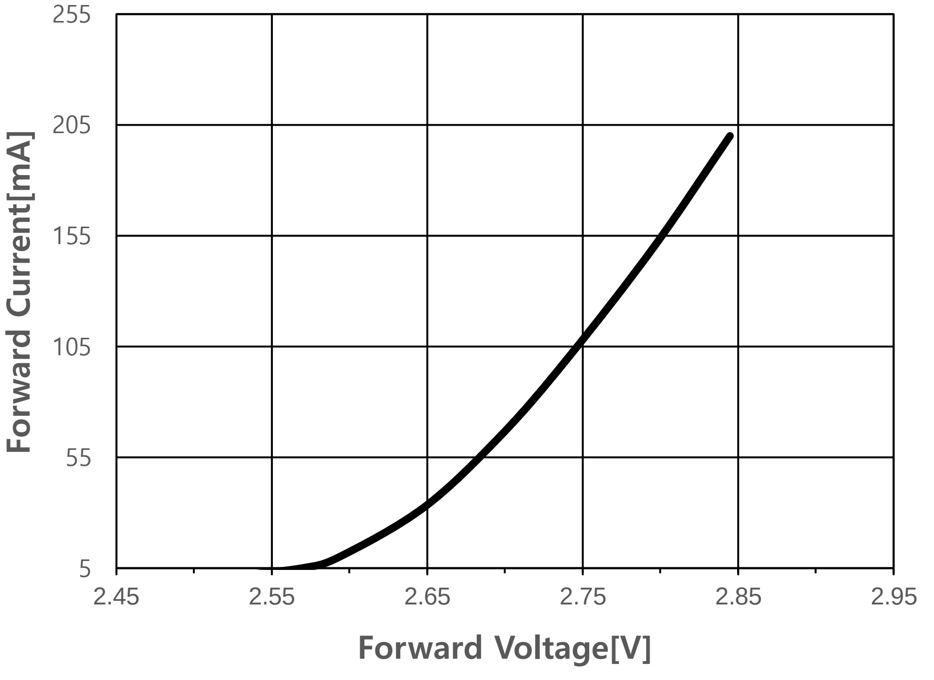
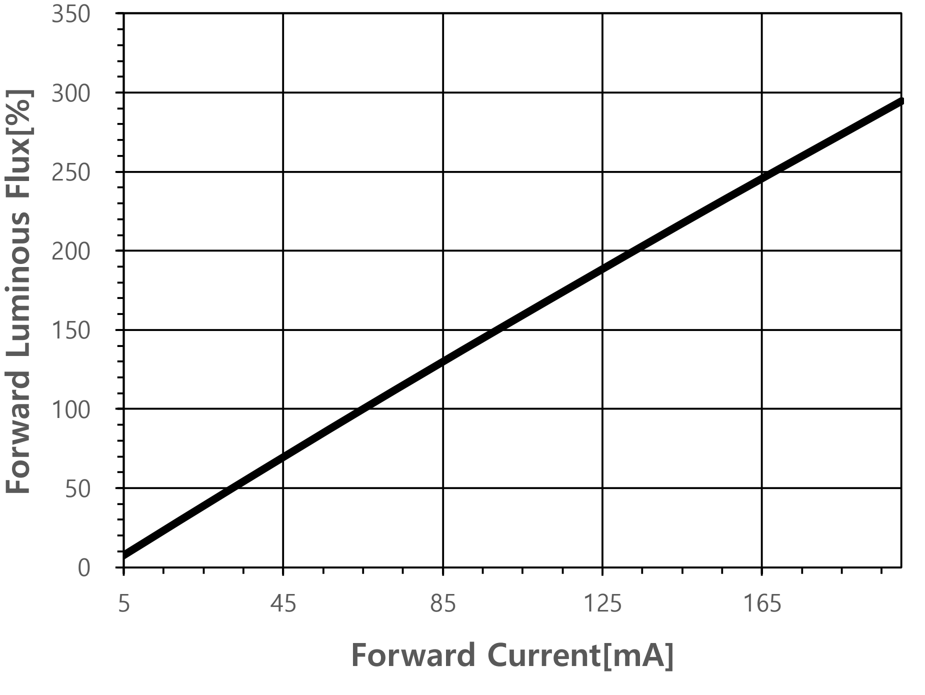


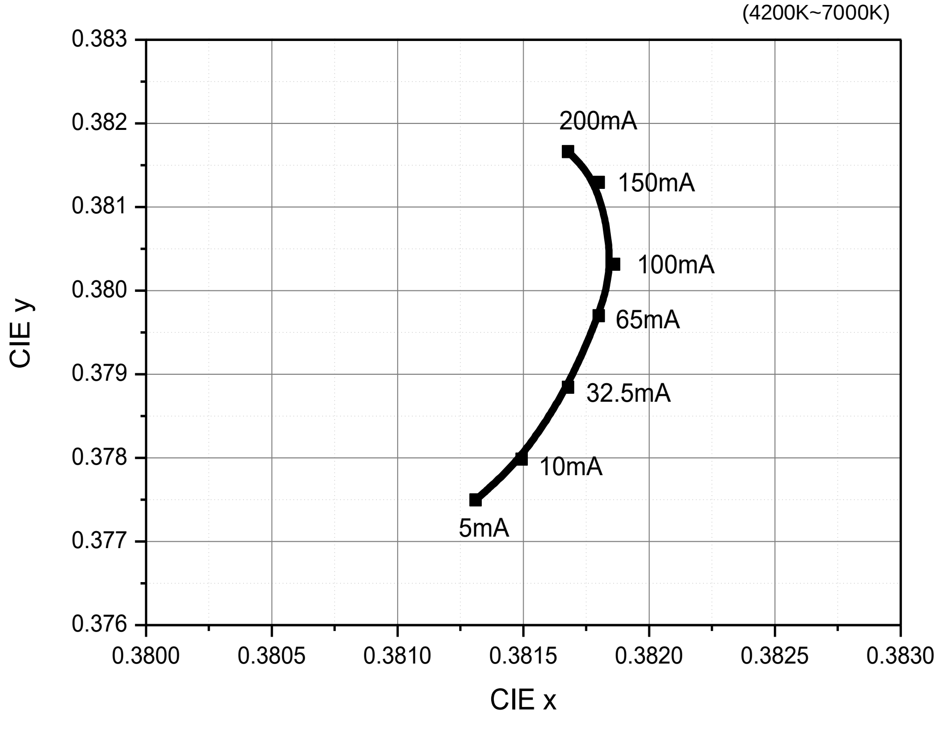
Fig 4. Forward Current vs. Relative Luminous Flux, T_j = 25ºC

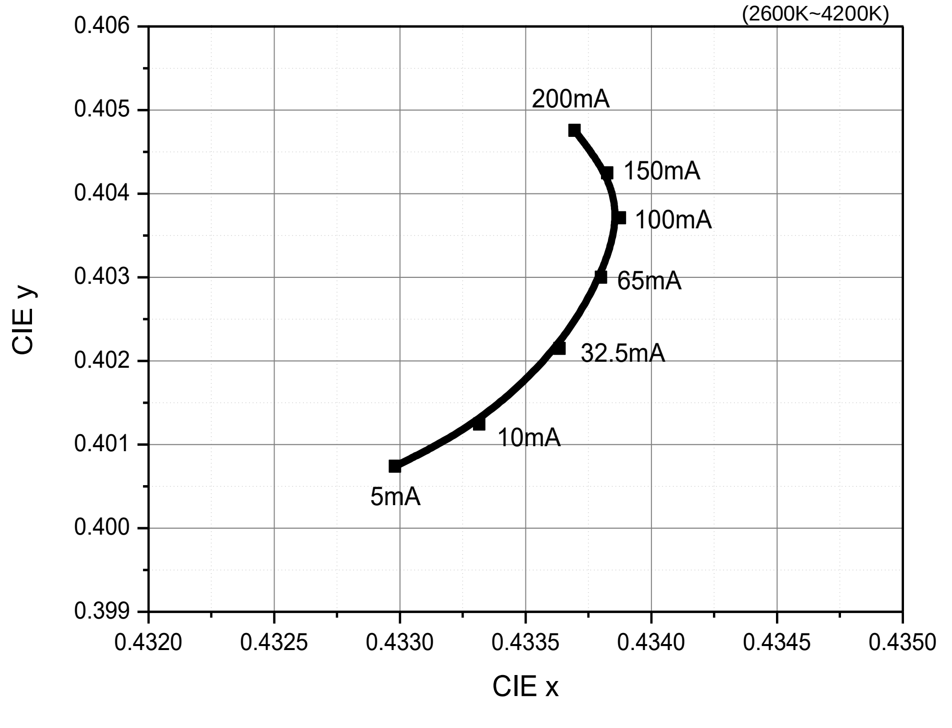


- Use of less than 5mA is not recommended

Characteristics Graph

Fig 5. Forward Current vs. CIE x, y Shift, T_j = 25ºC





Characteristics Graph

Fig 6. Junction Temperature vs. Relative Luminous Flux, I_F=65mA

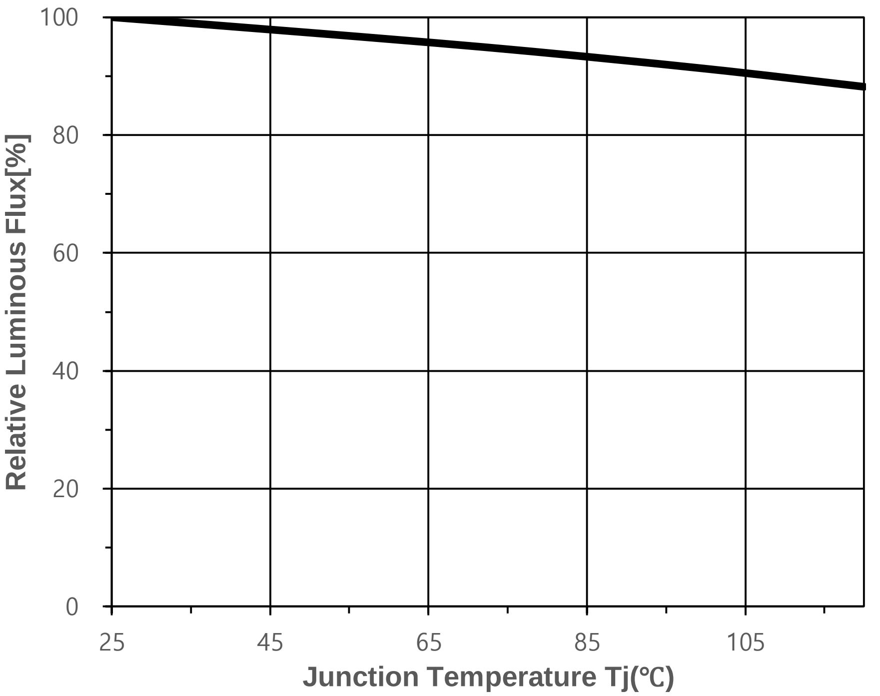
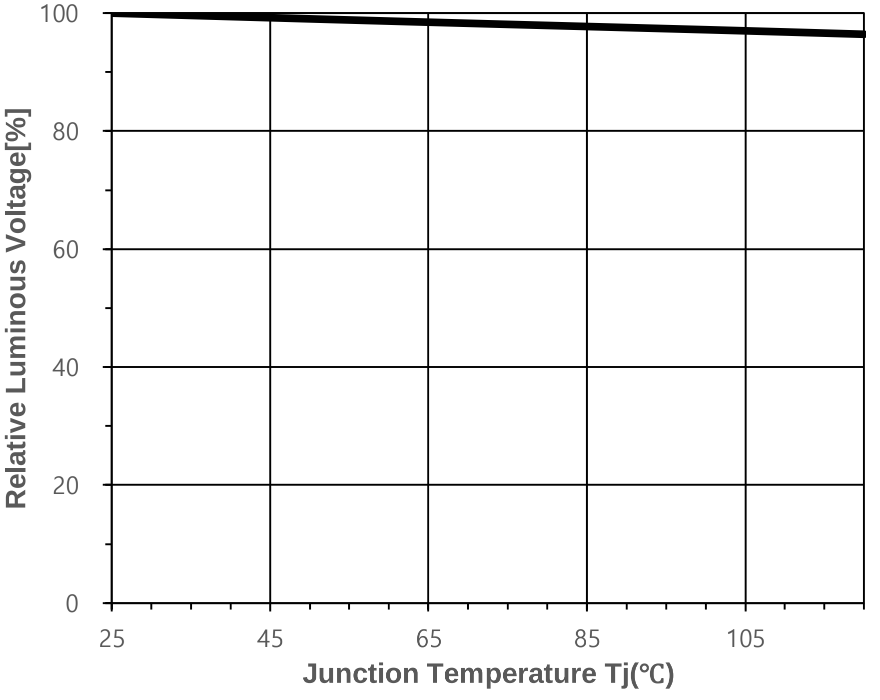
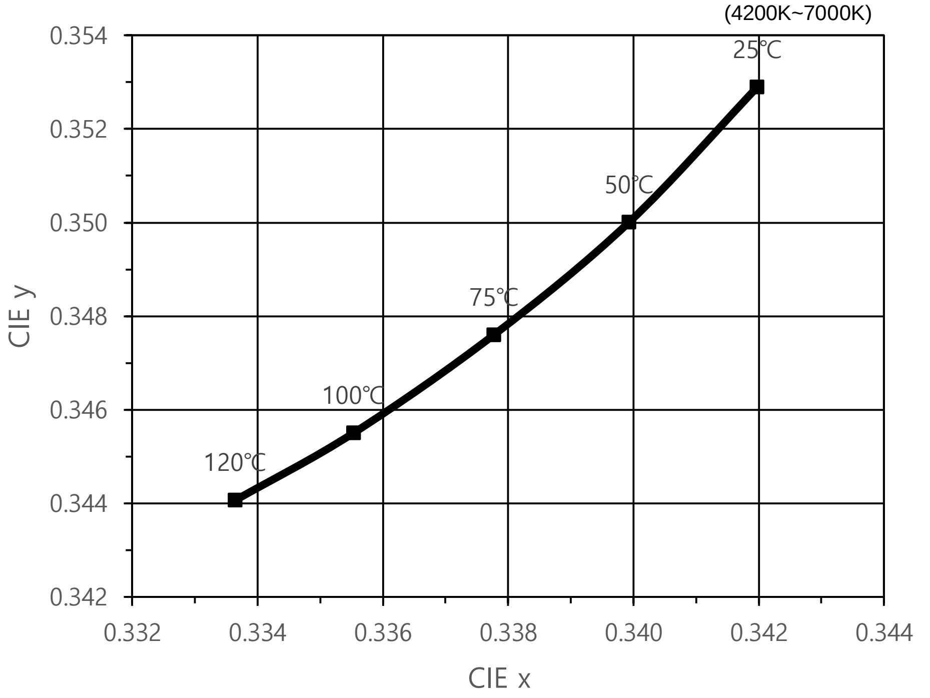


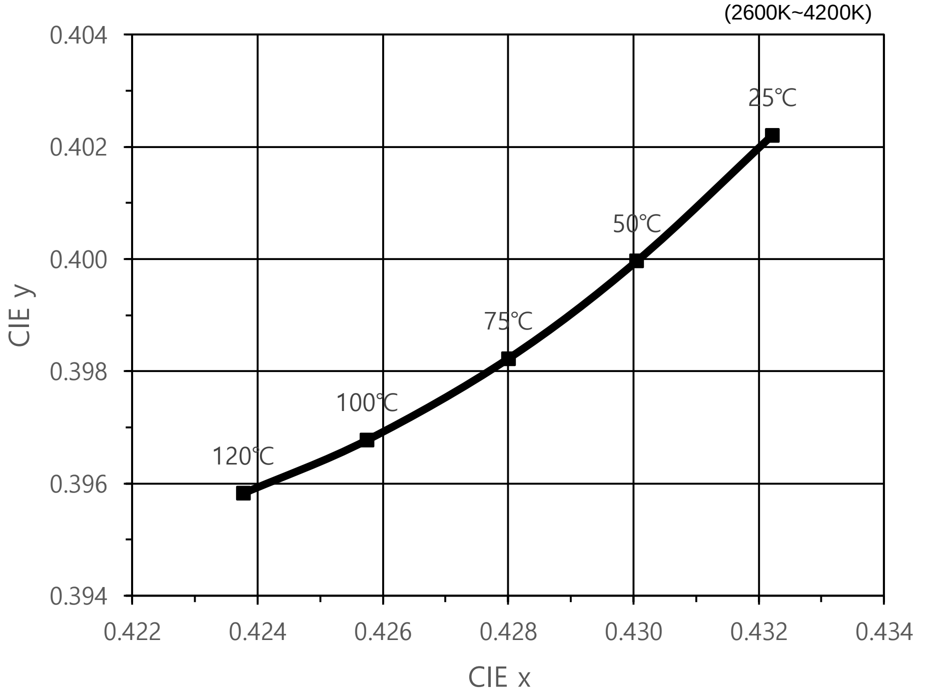
Fig 7. Junction Temperature vs. Relative Forward Voltage, I_F=65mA



Characteristics Graph

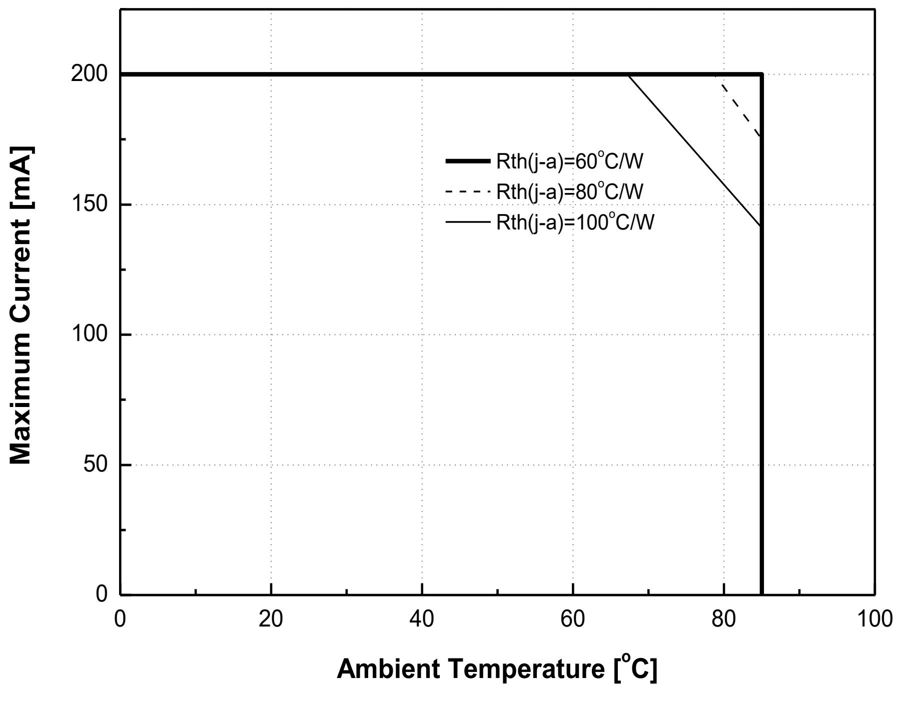
Fig 8. Chromaticity Coordinate vs. Junction Temperature, I_F=65mA





Characteristics Graph

Fig 9. Ambient Temperature vs. Maximum Forward Current, T_{j_max} = 125℃



Color Bin Structure

Table 5. Bin Code description, T_j=25℃, I_F=65mA

Part Number	Luminous Flux (lm)			Color Chromaticity Coordinate	Typical Forward Voltage (V)		
	Bin Code	Min.	Max.		Bin Code	Min.	Max.
STW8C12E-E00000IZ	V5	37.5	39.0	Refer to page 14-16.	Y0	2.60	2.70
	W0	39.0	40.5		Y1	2.70	2.80
	W5	40.5	42.0				

Table 6. Flux rank distribution

Available ranks (shaded)

CCT	CIE	Flux Rank		
6000 ~ 7000K	A	V5 (available)	W0 (available)	W5
5300 ~ 6000K	B	V5 (available)	W0 (available)	W5
4700 ~ 5300K	C	V5	W0 (available)	W5 (available)
3700 ~ 4200K	E	V5	W0 (available)	W5 (available)
3200 ~ 3700K	F	V5 (available)	W0 (available)	W5
2900 ~ 3200K	G	V5 (available)	W0 (available)	W5
2600 ~ 2900K	H	V5 (available)	W0 (available)	W5

*Notes :

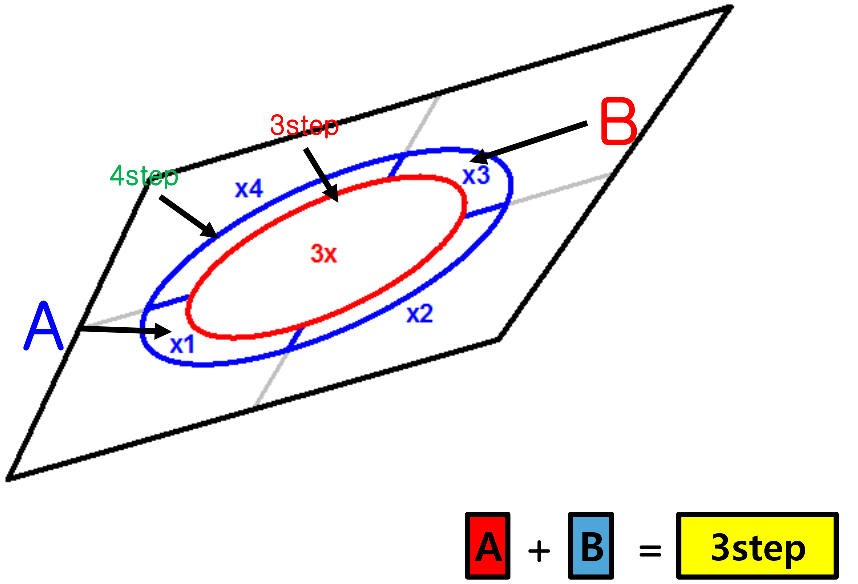
All measurements were made under the standardized environment of Seoul Semiconductor.

In order to ensure availability, single color rank will not be orderable.

Color Bin Structure

Guide : Kitting Solution of 4 sub bins

In multi-LED applications, creating a MacAdam 3-step from a variety of 4bins is a effective way to achieve good color quality while minimizing LED costs. In the below illustration, you will find how we can achieve the macadam 3-step using kitting 3-step/4-step ellipse bins.

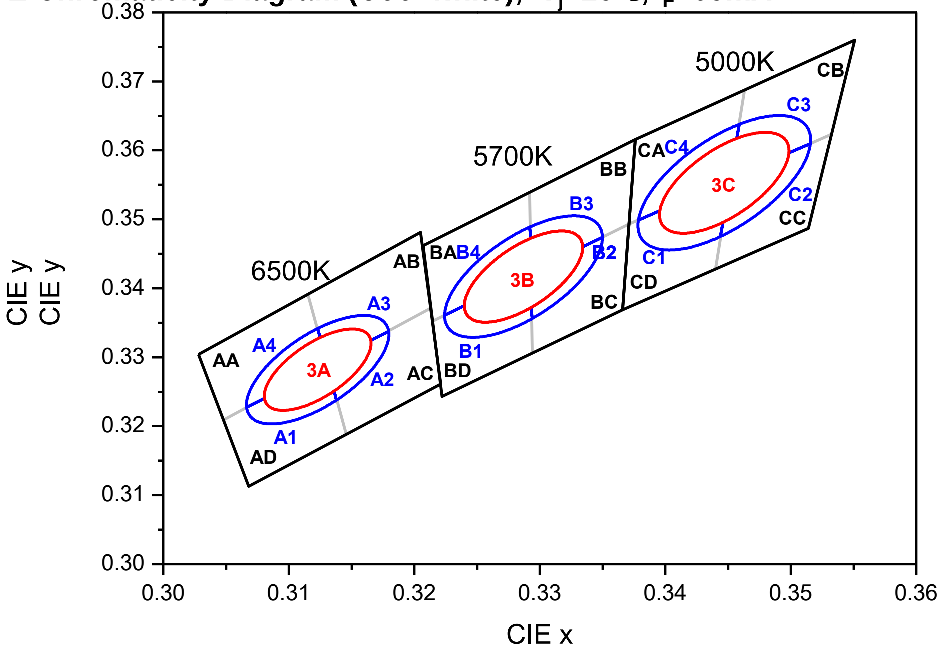


*** Only for reference**

Item	Bin #1	Bin #2	Note
CIE	3x	3x	3step Kitting
	x1	x3	4step Kitting
	x2	x4	
VF	Do not specify rank, randomly assigned.		N/A
LM	Do not specify rank, randomly assigned.		N/A

Color Bin Structure

CIE Chromaticity Diagram (Cool white), T_j=25℃, I_F=65mA



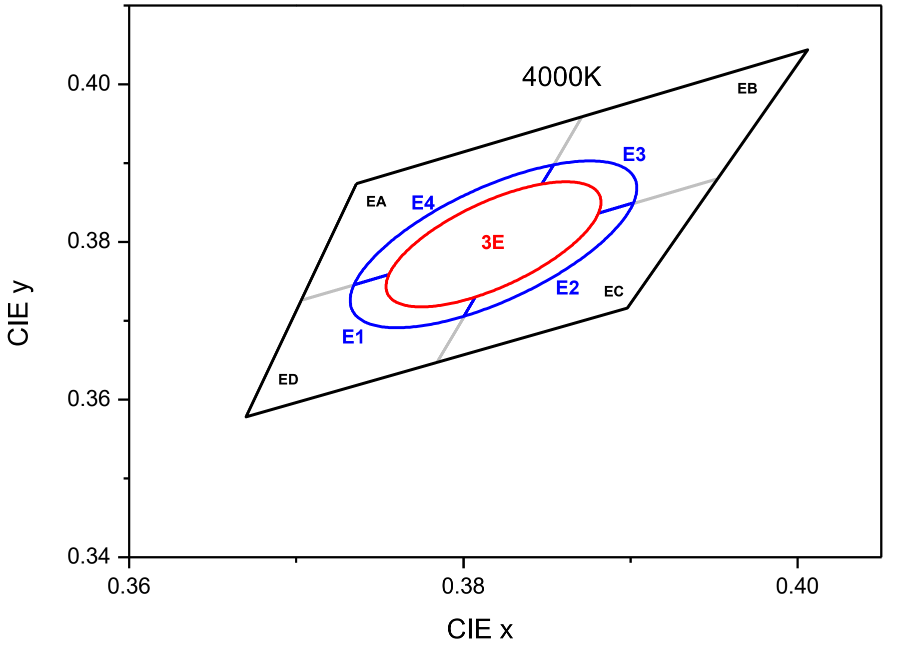
6500K 3Step		5700K 3Step		5000K 3Step	
3A		3B		3C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553
Major Axis a	0.0067	Major Axis a	0.0075	Major Axis a	0.0082
Minor Axis b	0.0029	Minor Axis b	0.0032	Minor Axis b	0.0035
Ellipse Rotation Angle	59	Ellipse Rotation Angle	59	Ellipse Rotation Angle	60

6500K 4Step		5700K 4Step		5000K 4Step	
4A		4B		4C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553
Major Axis a	0.0089	Major Axis a	0.0100	Major Axis a	0.0110
Minor Axis b	0.0038	Minor Axis b	0.0043	Minor Axis b	0.0047
Ellipse Rotation Angle	59	Ellipse Rotation Angle	59	Ellipse Rotation Angle	60

AA		AB		AC		AD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3028	0.3304	0.3115	0.3393	0.3131	0.3290	0.3048	0.3209
0.3048	0.3209	0.3131	0.3290	0.3146	0.3187	0.3068	0.3113
0.3131	0.3290	0.3213	0.3371	0.3221	0.3261	0.3146	0.3187
0.3115	0.3393	0.3205	0.3481	0.3213	0.3371	0.3131	0.3290
BA		BB		BC		BD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3207	0.3462	0.3292	0.3539	0.3293	0.3423	0.3215	0.3353
0.3215	0.3353	0.3293	0.3423	0.3294	0.3306	0.3222	0.3243
0.3293	0.3423	0.3371	0.3493	0.3366	0.3369	0.3294	0.3306
0.3292	0.3539	0.3376	0.3616	0.3371	0.3493	0.3293	0.3423
CA		CB		CC		CD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3376	0.3616	0.3463	0.3687	0.3452	0.3558	0.3371	0.3493
0.3371	0.3493	0.3452	0.3558	0.3440	0.3428	0.3366	0.3369
0.3452	0.3558	0.3533	0.3624	0.3514	0.3487	0.3440	0.3428
0.3463	0.3687	0.3551	0.3760	0.3533	0.3624	0.3452	0.3558

Color Bin Structure

CIE Chromaticity Diagram (Neutral white), T_j=25℃, I_F=65mA



4000K 3Step

3E	
Center point	0.3818 : 0.3797
Major Axis a	0.0094
Minor Axis b	0.0040
Ellipse Rotation Angle	54

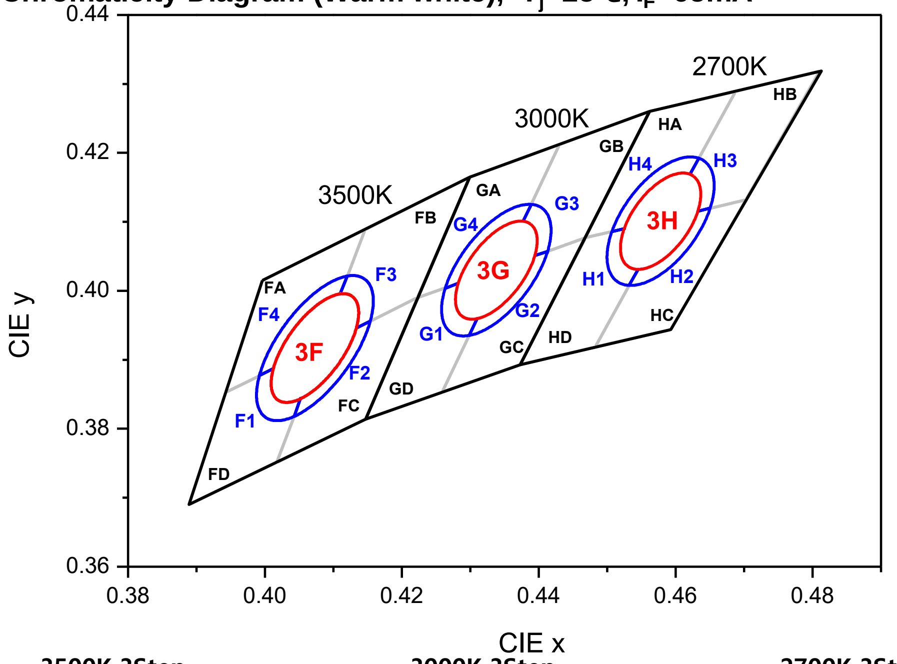
4000K 4Step

4E	
Center point	0.3818 : 0.3797
Major Axis a	0.0125
Minor Axis b	0.0054
Ellipse Rotation Angle	54

EA		EB		EC		ED	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3736	0.3874	0.3871	0.3959	0.3828	0.3803	0.3703	0.3726
0.3703	0.3726	0.3828	0.3803	0.3784	0.3647	0.3670	0.3578
0.3828	0.3803	0.3952	0.3880	0.3898	0.3716	0.3784	0.3647
0.3871	0.3959	0.4006	0.4044	0.3952	0.3880	0.3828	0.3803

Color Bin Structure

CIE Chromaticity Diagram (Warm white), T_j=25℃, I_F=65mA



3500K 3Step	
3F	
Center point	0.4073 : 0.3917
Major Axis a	0.0093
Minor Axis b	0.0041
Ellipse Rotation Angle	54

3000K 3Step	
3G	
Center point	0.4338 : 0.4030
Major Axis a	0.0083
Minor Axis b	0.0041
Ellipse Rotation Angle	53

2700K 3Step	
3H	
Center point	0.4578 : 0.4101
Major Axis a	0.0081
Minor Axis b	0.0042
Ellipse Rotation Angle	54

3500K 4Step	
4F	
Center point	0.4073 : 0.3917
Major Axis a	0.0124
Minor Axis b	0.0055
Ellipse Rotation Angle	54

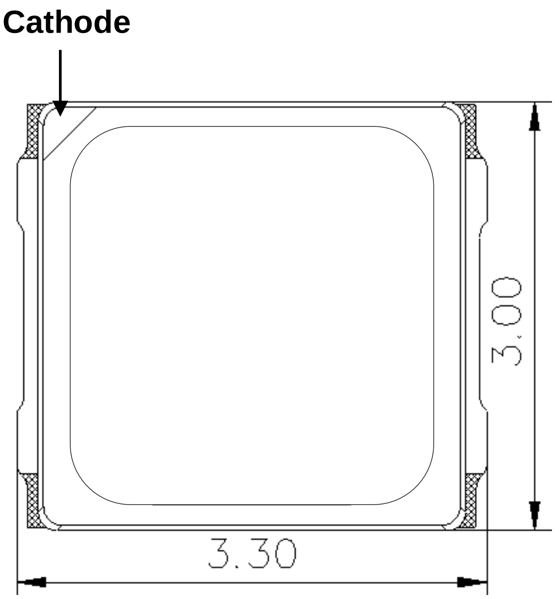
3000K 4Step	
4G	
Center point	0.4338 : 0.4030
Major Axis a	0.0112
Minor Axis b	0.0054
Ellipse Rotation Angle	53

2700K 4Step	
4H	
Center point	0.4578 : 0.4101
Major Axis a	0.0108
Minor Axis b	0.0056
Ellipse Rotation Angle	54

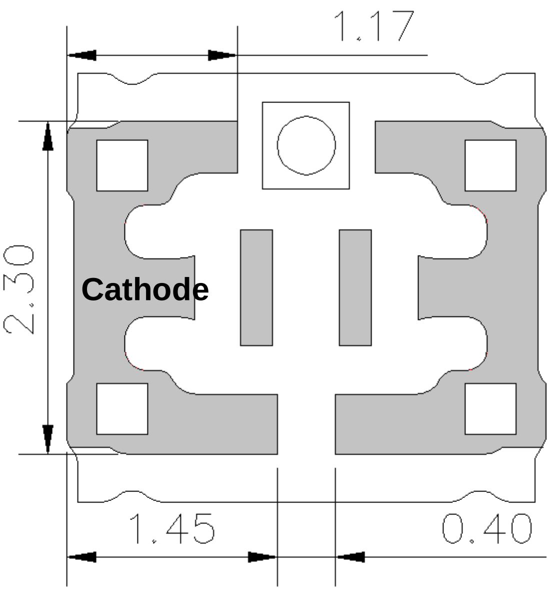
FA		FB		FC		FD	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3996	0.4015	0.4146	0.4089	0.4082	0.3920	0.3943	0.3853
0.3943	0.3853	0.4082	0.3920	0.4017	0.3751	0.3889	0.3690
0.4082	0.3920	0.4223	0.3990	0.4147	0.3814	0.4017	0.3751
0.4146	0.4089	0.4299	0.4165	0.4223	0.3990	0.4082	0.3920
GA		**GB**		**GC**		**GD**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4299	0.4165	0.4430	0.4212	0.4345	0.4033	0.4223	0.3990
0.4223	0.3990	0.4345	0.4033	0.4259	0.3853	0.4147	0.3814
0.4345	0.4033	0.4468	0.4077	0.4373	0.3893	0.4259	0.3853
0.4430	0.4212	0.4562	0.4260	0.4468	0.4077	0.4345	0.4033
HA		**HB**		**HC**		**HD**	
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4562	0.4260	0.4687	0.4289	0.4585	0.4104	0.4468	0.4077
0.4468	0.4077	0.4585	0.4104	0.4483	0.3919	0.4373	0.3893
0.4585	0.4104	0.4703	0.4132	0.4593	0.3944	0.4483	0.3919
0.4687	0.4289	0.4810	0.4319	0.4703	0.4132	0.4585	0.4104

Mechanical Dimensions

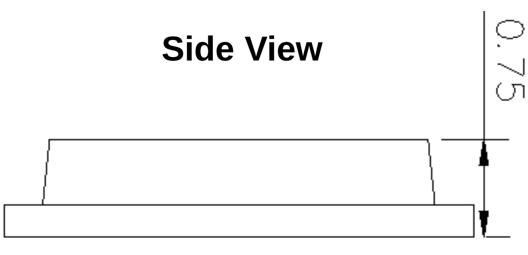
Top View



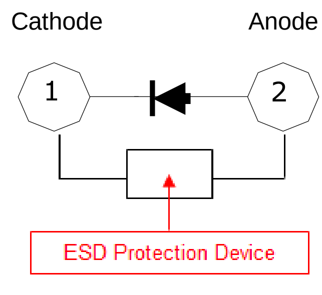
Bottom (Transmittance) View



Side View

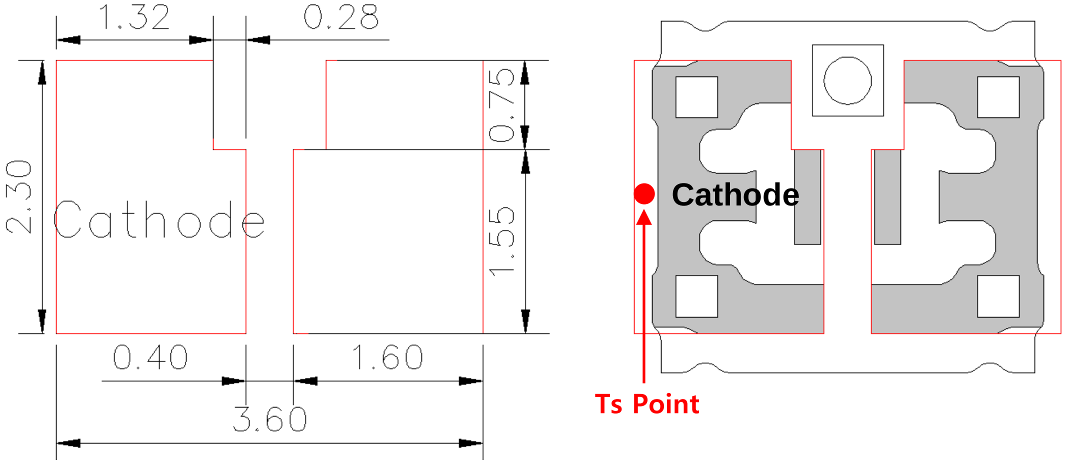


Circuit



(1) All dimensions are in millimeters.
(2) Scale : none
(3) Undefined tolerance is ±0.07mm

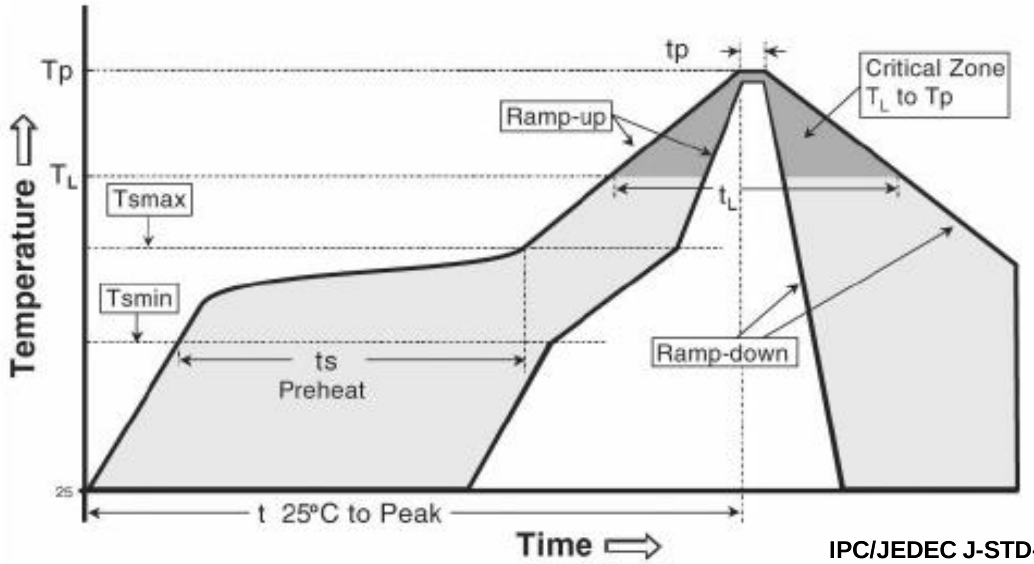
Recommended Solder Pad



Notes :

(1) All dimensions are in millimeters.
(2) Scale : none
(3) This drawing without tolerances are for reference only
(4) Undefined tolerance is ±0.1mm

Reflow Soldering Characteristics



IPC/JEDEC J-STD-020

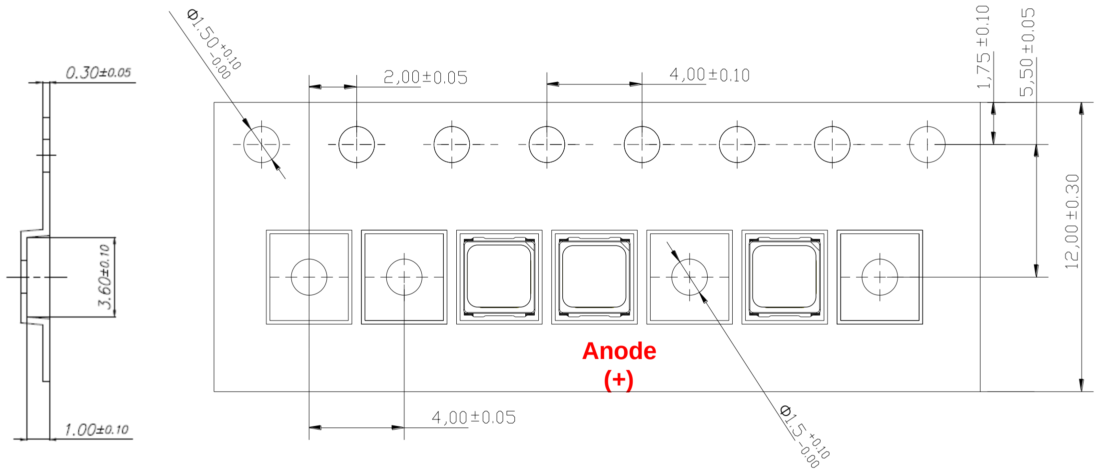
Table 7.

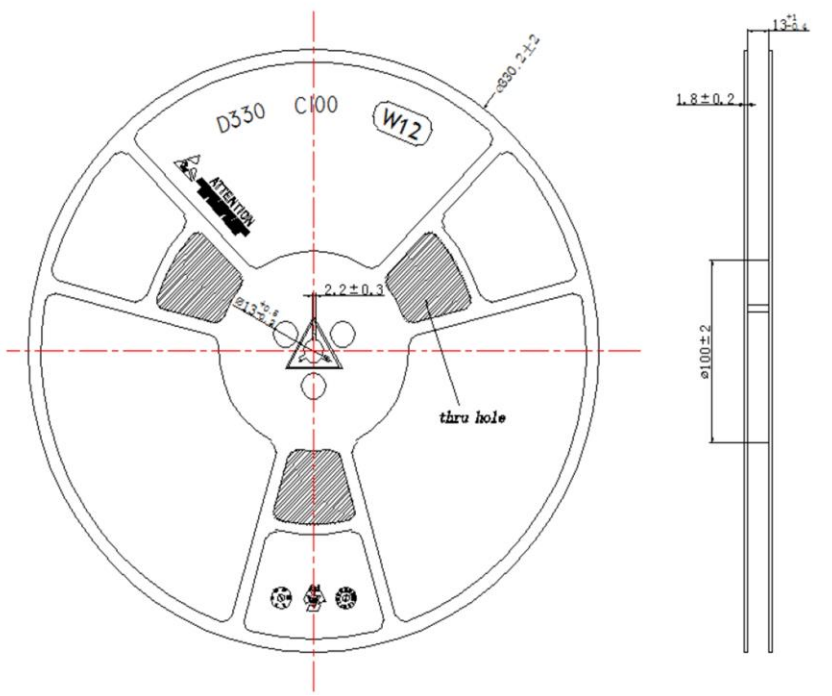
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	 100 °C 150 °C 60-120 seconds	 150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (TL) - Time (tL)	 183 °C 60-150 seconds	 217 °C 60-150 seconds
Peak Temperature (Tp)	215℃	260℃
Time within 5°C of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Caution

(1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
(2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
(3) Die slug is to be soldered.
(4) When soldering, do not put stress on the LEDs during heating.
(5) After soldering, do not warp the circuit board.

Emitter Tape & Reel Packing





(Tolerance: ±0.2, Unit: mm)

Note :

(1) Quantity : 12,000pcs/Reel

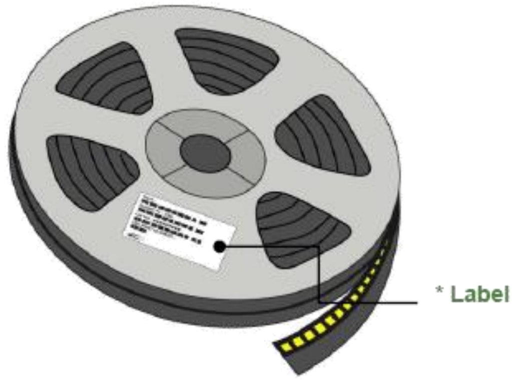
(2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ±0.2mm

(3) Adhesion Strength of Cover Tape
Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10˚ to the carrier tape.

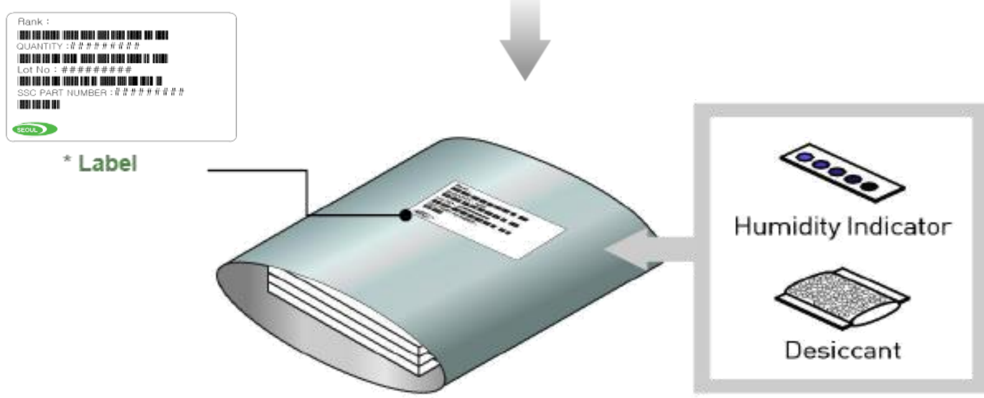
(4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.

Emitter Tape & Reel Packing

Reel



Aluminum Bag



Outer Box

Product Nomenclature

Table 8. Part Numbering System : $X_1X_2X_3X_4X_5X_6X_7X_8$-X_9X_{10}

Code	Description	Part Number	Value
X_1	Company	S	
X_2	Top View LED series	T	
X_3X_4	Color Specification	W8	CRI 80
X_5	Package series	C	C series
X_6X_7	Characteristic code	12	
X_8	Revision	E	
X_9X_{10}	Characteristic	E0	

S	1	W	0	-	3	0	3	0	x	x	8	0	0	3	-	0	0	0	0	0	0	0	0	-	0	0	0	1	1
X_1	X_2	X_3	X_4	X_5	X_6	X_7	X_8	X_9	X_{10}	X_{11}	X_{12}	X_{13}	X_{14}	X_{15}	X_{16}	X_{17}	X_{18}	X_{19}	X_{20}	X_{21}	X_{22}	X_{23}	X_{24}	X_{25}	X_{26}	X_{27}	X_{28}	X_{29}	X_{30}

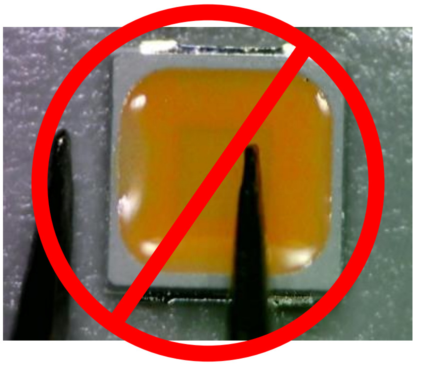
Code	Description	Order Code	Value
X_1	Company	S	Seoul Semiconductor
X_2	Level of Integration	1	Discrete LED
X_3X_4	Technology	W0	General White
X_5	-		
$X_6X_7X_8X_9$	Dimension	3030	
$X_{10}X_{11}$	CCT	xx	
$X_{12}X_{13}$	CRI	80	
$X_{14}X_{15}$	Vf	03	
X_{16}	-		
$X_{17}X_{18}X_{19}$	Characteristic code Flux Rank	000	
$X_{20}X_{21}X_{22}$	Characteristic code Vf Rank	000	
$X_{23}X_{24}$	Characteristic code Color Step	00	
X_{25}	-		
$X_{26}X_{27}$	Type	00	
$X_{28}X_{29}X_{30}$	Internal code	011	

Table 9. Lot Numbering System :$Y_1Y_2Y_3Y_4Y_5Y_6Y_7Y_8Y_9Y_{10}$–$Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$

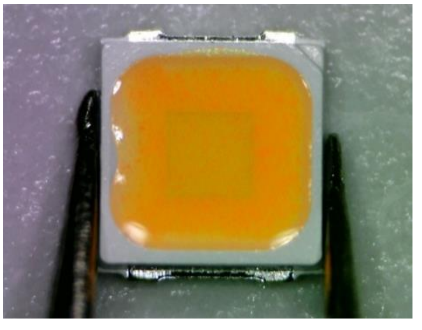
Lot Number Code	Description	Lot Number	Value
Y_1Y_2	Year		
Y_3	Month		
Y_4Y_5	Day		
Y_6	Top View LED series		
$Y_7Y_8Y_9Y_{10}$	Mass order		
$Y_{11}Y_{12}Y_{13}Y_{14}Y_{15}Y_{16}Y_{17}$	Internal Number		

Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.
Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this. product with acid or sulfur material in sealed space.

Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant.

The recommended storage temperature range is 5℃ to 30℃ and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMT techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

a. Recommend conditions after opening the package

- Sealing
- Temperature : 5 ~ 30℃ Humidity : less than RH60%

b. If the package has been opened more than 4 week(MSL_2a) or the color of the desiccant changes, components should be dried for 10-24hr at 65±5℃

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication.

These products are dangerous if they are burned or shredded in the process of disposal.

It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.

When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

Precaution for Use

(10) The appearance and specifications of the product may be modified for improvement without notice.

(11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

(12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(13) Attaching LEDs, do not use adhesives that outgas organic vapor.

(14) The driving circuit must be designed to allow forward voltage only when it is ON or OFF.
If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

(15) Similar to most Solid state devices;
LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS).
Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event.
One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
  (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package
  (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device

Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world’s fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as “nPola”, "Acrich", the world’s first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company’s broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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